

795nm Mercury™ Series High-Power Single-Frequency Laser Diode PH795DBRXXXTS

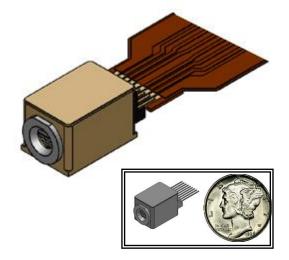
Technology

- DBR Single-Frequency Laser Chip
- AlGaAs QW Active Layer

Photodigm VV+

Features

- Robust, monolithic die design
- Pulsed operation for spectral stability at short pulse lengths
- Package contains TEC cooling with precise thermistor control
- High Slope Efficiency
- Hermetic package for high reliability



Description

The 795nm Mercury[™] series of high-power edge-emitting lasers are based on Photodigm's advanced single-frequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam in a compact hermetic package. Facets are passivated for high-power reliability. Applications include mobile spectroscopy instrumentation where durability and reliability are essential.

Absolute Maximum Ratings

Parameter	Symbol	Unit	Min	Max
Storage Temperature	T _{STG}	С°	0	80
Operating Temperature	T _{OP}	С°	5.0	70
CW Laser Forward Current, T=25°C	١ _F	mA	-	**
Laser Reverse Voltage	V _R	V	-	0.0
TEC Current	I _{TEC}	А	-1.1	1.1
TEC Voltage	V _{TEC}	V	-3.0	3.0
Thermistor Current	I _{THRM}	mA	-	1.0
Thermistor Voltage	V _{THRM}	V	-	10

**Do not exceed drive current or operating power of supplied LIV

Photodigm VVAA

Side Mode Suppression Ratio

Laser Polarization

Mode Structure

PRODUCT BULLETIN

-

TE

Fundamental Mode

Max

797

-

80

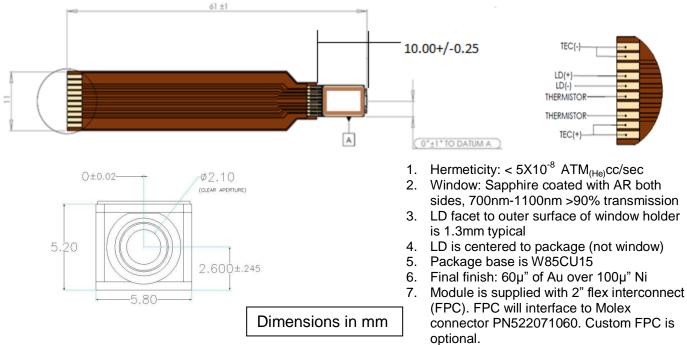
2.5

2.5

-1.0

8 X 32

CW Characteristics at T_c = 25°C unless otherwise specified **Symbol** Parameter Unit Min Тур Center Wavelength @ 150mA 793 795 nm λ_c **Optical Output Power** P_{o} mW See Power Options Call-out Slope Efficiency W/A 0.75 0.85 η_d Threshold Current 50 I_{th} mΑ Laser Series Resistance Ω 2.0 Rs -Laser Forward Voltage @ 150mA V 2.0 VF -Thermistor Resistance @ 25°C KΩ R_T -10 Laser Line Width MHz 0.5 Δv _ Beam Divergence @ FWHM θιι Χ θ⊥ 0 -6 X 28



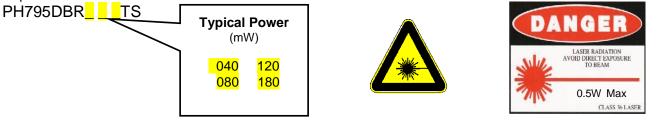
SMSR

dB

-30

How To Order

Part number example: PH795DBR080TS. Assign optical power from those available. Use a three-digit format for all power entries. These devices are sensitive to ESD.



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